Recommended Test Procedures for Operational Amplifiers

Introduction

The following text describes the basic test procedures that can be used for most Intersil Op Amps. Note that all measurement conversions have been taken into account in the equations stated.

1. Offset Voltage

The offset voltage (V_{IO}) of the amplifier under test (AUT) is measured via Test Circuit 1 as follows:

1. Set V+ and V- supplies to values specified in Table 1, Column (1) and V_{DC} to 0V.
2. Close S_1 and S_2, open S_3.
3. Choose: R_F = 50K for non-precision amplifiers.
   R_F = 5M for precision amplifiers.
4. Measure voltage at E in volts (label as E_1).

   $V_{IO} = E_1$ (mV) for R_F = 50K, or

   $V_{IO} = E_1 *10$ (μV) for R_F = 5M

The gain of this circuit with R_F = 50K (R_F = 5M) requires the output to be driven to 1000 (100,000) times the offset voltage necessary to maintain the output of the AUT at 0V. Note that the AUT output is always identical to V_{DC}. Overall circuit stability is maintained by the adjustable feed-back capacitor C_A.

2. Input Bias Current

The bias current flowing in or out of the positive terminal of the AUT (I_B+) is obtained using Test Circuit 1 by:

1. Measuring E_1 as in procedure 1 (use R_S = 100K for JFET input devices).
2. Maintain V_{DC} at 0V.
3. Close S_2, open S_1 and S_3.
4. Measuring voltage at E in volts (label as E_2).

   $I_{B+} = (E_1 - E_2)$ x 100 (nA) for R_F = 50K, R_S = 10K, or

   $I_{B+} = (E_1 - E_2)$ x 10 (nA) for R_F = 50K, R_S = 100K

The bias current flowing in or out of the negative terminal (I_{B-}) is found by:

1. Following steps 1 and 2 for I_B+.
2. Close S_1, open S_2 and S_3.
3. Measuring voltage at E in volts (label as E_3).

   $I_{B-} = (E_1 - E_3)$ x 100 (nA) for R_F = 50K, R_S = 10K, or

   $I_{B-} = (E_1 - E_3)$ x 10 (nA) for R_F = 50K, R_S = 100K

3. Input Offset Current

Using Test Circuit 1, the input offset current (I_{IO}) of the AUT is determined by:

1. Measuring E_1 as in procedure 1.
2. Maintaining V_{DC} at 0V.
3. Open S_1, S_2 and S_3.

4. Measuring voltage at E in volts (label as E_4).

   $I_{IO} = (E_1 - E_4)$ x 100 (nA) for R_F = 50K, R_S = 10K, or

   $I_{IO} = (E_1 - E_4)$ x 10 (nA) for R_F = 50K, R_S = 100K

4. Power Supply Rejection Ratio

Both positive and negative PSRRs are measured via Test Circuit 1. For PSRR+:

1. Close S_1 and S_2, open S_3.
2. Choose: R_F = 50K
3. Set V_{DC} = 0, V+ = 10V, and V- = -15V.
4. Measure voltage at E in volts (label as E_5).
5. Change V+ to +20V.
6. Measure voltage at E in volts (label as E_6).

$$PSRR + = 20 \log_{10} \left| \frac{10^4}{E_5 - E_6} \right| (dB) \text{ for } R_F = 50K$$

Similarly for PSRR-:

1. Follow steps 1 and 2 for PSRR+ above.
2. Set V_{DC} = 0V, V+ = +15V, V- = -10.
3. Measure voltage at E in volts (label as E_7).
4. Change V- to -20V.
5. Measure voltage at E in volts (label as E_8).

$$PSRR - = 20 \log_{10} \left| \frac{10^4}{E_7 - E_8} \right| (dB) \text{ for } R_F = 50K$$

5. Common Mode Rejection Ratio

The CMRR is determined by adjusting Test Circuit 1 as follows:

1. Close S_1 and S_2, open S_3.
1. Choose: R_F = 50K
2. Set V+ = +5V, V- = -25V, and V_{DC} = -10V.
3. Measure voltage at E in volts (label as E_9).
4. Set V+ = 25V, V- = -5V, and V_{DC} = 10V.
5. Measure voltage at E in volts (label as E_{10}).

$$CMRR = 20 \log_{10} \left| \frac{2 \times 10^4}{E_9 - E_{10}} \right| (dB) \text{ for } R_F = 50K$$

6. Output Voltage Swing

Test Circuit 2 is adjusted to measure V_{OUT}+ and V_{OUT}- the procedure is:

1. Select appropriate V+ and V- supply values from Table 1, Column 1.
2. Select specified R_L from Table 1, Column 2.

3. Set V_{IN} = 0.5V.

4. Measure voltage at E in volts. V_{OUT+} = E (V)

Similarly V_{OUT-} is found by:

1. Selecting specified R_L from Table 1, Column 1.

2. Setting V_{IN} = -0.5V.

3. Measuring voltage at E in volts.
   V_{OUT-} = E (V)

7. Output Current

The output current corresponding to the output voltage of procedure 6 is found by:

1. Measuring V_{OUT-} and V_{OUT+} as in procedure 6.

$$I_{OUT} = \frac{V_{OUT+}}{R_L} \quad \text{where } R_L \text{ is from Table 1, Column 2.}$$

$$I_{OUT} = \frac{V_{OUT-}}{R_L} \quad \text{where } R_L \text{ is from Table 1, Column 2.}$$

8. Open Loop Gain

Both positive ($A_{VOL}+$) and negative ($A_{VOL}-$) open loop gain measurements are determined by adjusting Test Circuit 1.

For $A_{VOL}+$:

1. Close S_1, S_2 and S_3.

2. Select specified R_L from Table 1, Column 3.

3. Set R_F = 50K.

4. Set V_{DC} = 0V, V+ = +15V, and V- = -15V.

5. Measure voltage at E in volts (label as E_{13}).

6. Set V_{DC} = 10V.

7. Measure voltage at E in volts (label as E_{14}).

$$A_{VOL+} = \frac{10}{E_{14} - E_{13}} (V/mV) \text{ for } R_F = 50K$$

For $A_{VOL}-$:

1. Follow steps 1, 2, 3, 4, and 5 above.

2. Set V_{DC} = -10V.

3. Measure voltage at E in volts (label as E_{15}).

$$A_{VOL}- = \frac{10}{E_{13} - E_{15}} (V/mV) \text{ for } R_F = 50K$$

9. Slew Rate

Test Circuit 3 is used for measurement of positive and negative slew rate. For SR+:

1. Select specified R_L, A_{CL}, and C_L from Table 1, Columns 4, 5 and 6.

2. Apply a positive step voltage to V_{AC} (refer to data book for test waveform).

3. Observe ΔV and Δt at E. A standard approach is to use the 10% and 90% points or else the 25% and 75% points on the waveform.
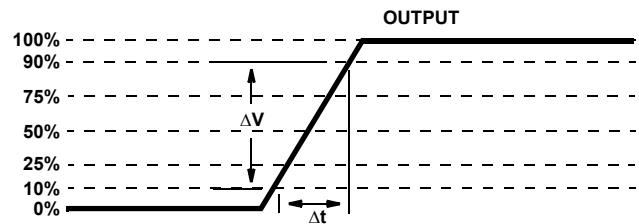
$$SR = \frac{\Delta V}{\Delta t}$$

For SR- repeat above procedure with negative input pulse.

$$SR- = \frac{\Delta V}{\Delta t}$$

## 10. Full Power Bandwidth

Full power bandwidth is calculated by:

1. Measuring slew rate as above in procedure 9.

2. Measuring V_{OUT+} as in procedure 6. (Typically V_{OUT+} is assumed to be the guaranteed minimum V_{OUT}, usually 10V.)

$$FPBW = \frac{SR+}{2\pi V_{OUT(PEAK)}}$$

11. Rise Time, Fall Time and Overshoot

The small signal step response of the AUT is determined via Test Circuit 3. The procedure requires:

1. Selecting the appropriate R_L, A_{CL}, and C_L from Table 1, Columns 4, 5 and 6.

2. Applying a positive input step voltage for rise time t_R and positive overshoot OS+.

   Applying a negative input step voltage for fall time t_F and negative overshoot OS-.

   (Refer to data book for input waveforms.)

3. Observe output of AUT noting the key points as shown.
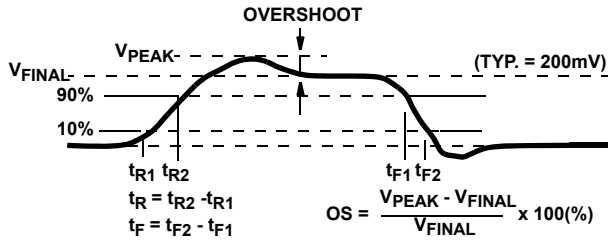
12. Settling Time

Test Circuit 6 is appropriate for settling time (t_S) measurement, the procedure is:

1. Select R_1 and R_2 such that AUT is at the A_{CL} stated in Table 1, Column 5.

2. Select R_3 and R_4 so that $R_3 \geq 2R_1$ and $R_4 \geq 2R_2$ with the condition that the ratio

$$\frac{R_3}{R_4} = \frac{R_1}{R_2} \text{ be maintained.}$$

3. Apply step voltage as specified in data book.

4. Measure the time from t_1 (time input step applied) to t_2 (the time E_S settles to within a specified percentage of V_{OUT} - see data book). $t_S = t_2 - t_1$

NOTE: Clipping diodes of Test Circuit 6 prevent overdrive of oscilloscope. (Recommend fast Schottky diodes.)

13. Gain Bandwidth Product

Test Circuit 4 is used for measuring GBP. The procedure is:

1. Sweep V_{IN} thru the required frequency range.

2. With a network analyzer view gain (dB) versus frequency as below.
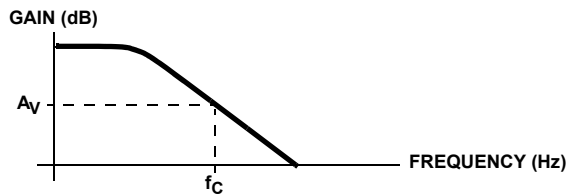
3. At the voltage gain of interest (A_V) determine the corresponding frequency f_C. Note that chosen A_V must be greater than or equal to that stated in column 5 of Table 1. GBP = $A_V \times f_C$ (Hz) where A_V is in V/V.

14. Phase Margin (Network Analyzer Method)

Test Circuit 4 is used to obtain phase margin measurement. The procedure is:

1. Sweep V_{IN} thru the required frequency range.

2. Display gain in dB and phase in degrees versus frequency on analyzer as shown.
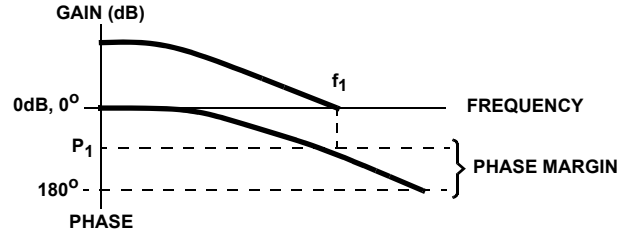
3. At a gain of 0dB (if A_{CL} = 1 in Table 1, column 5), record frequency f_1 and corresponding phase P_1.
Phase margin = 180 degrees - P_1 degrees.

15. Input Noise Voltage

Test Circuit 5 is designed for measuring input noise voltage. Use of the Quantec Noise Analyzer is recommended to obtain measurements at 1Hz bandwidth around a specific center frequency. The procedure is:

1. Set R_G = 0

2. Set circuit card to gain of 10.

3. Select measurement frequency of interest.

4. Record noise voltage (label as E_{n1}). Units are nV/$\sqrt{\text{Hz}}$.

16. Input Noise Current

Using Test Circuit 5, the input noise current is obtained by:

1. Measure E_{n1} as above for the desired frequency of interest.

2. Adjust R_G so that $V_O > 2E_{n1}$ (label V_O as E_{n2}).

$$I_n = \sqrt{\frac{(E_{n2})^2 - (E_{n1})^2 - 4kTR_G}{R_G^2}}$$

Where K = 1.38 x 10^{-23} (Boltzmann's Constant)
T = 300°C (27°C)

17. Channel Separation (Crosstalk)

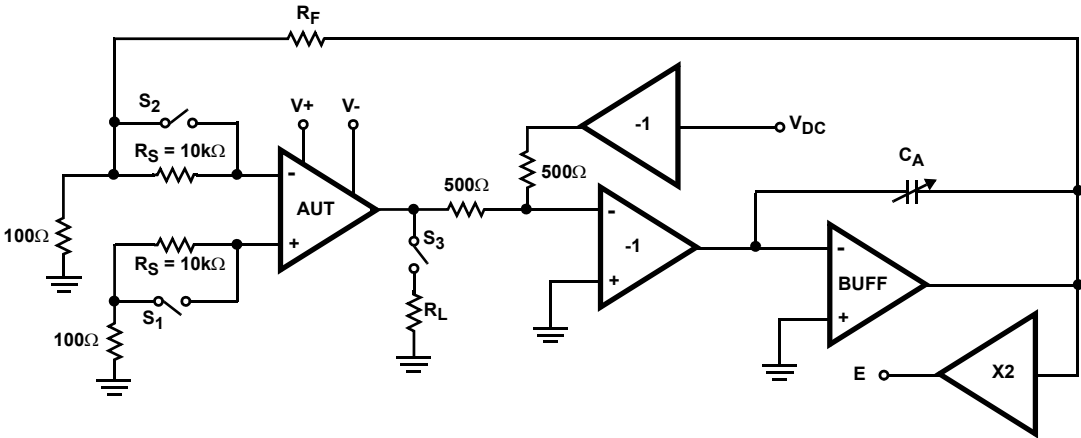Test Circuit 7 is used to measure channel separation (CS). The procedure is as follows:

1. Apply V_{IN} at the frequency of interest to input of channel 1.

2. Select R_L from Table 1, column 4.

3. Measure V_{O1}.

4. Measure V_{O2} of channel 2.

$$CS = 20 \log_{10}\left|\frac{V_{O2}}{100V_{O1}}\right| dB$$

TABLE 1.

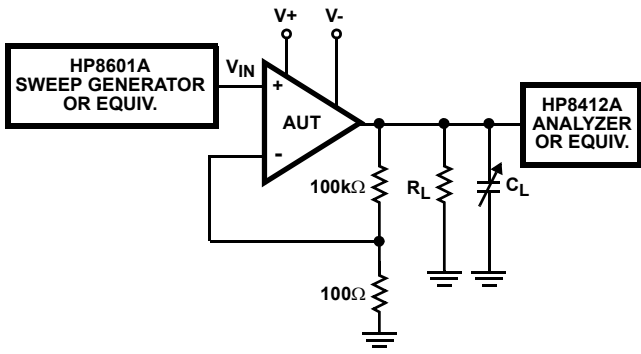| PART NUMBER	(1) SUPPLY VOLTAGE (V_S)	PARAMETERS TO MEASURE				
		(2) V_{OUT} R_L(kΩ)	(3) A_{VOL} R_L(kΩ)	SLEW RATE, OS, t_R, t_F		
				(4) R_L(kΩ)	(5) A_{CL}	(6) C_L(pF)
HA-2400/04/05	±15	2	2	2	1	50
HA-2500/02/05	±15	2	2	2	1	50
HA-2510/12/15	±15	2	2	2	1	50
HA-2520/02/05	±15	2	2	2	3	50
HA-2539	±15	1	1	1	10	10
HA-2540	±15	1	1	1	10	10
HA-2541	±15	2	2	2	1	10
HA-2542	±15	1	1	1	2	10
HA-2600/02/05	±15	2	2	2	1	100
HA-2620/02/05	±15	2	2	2	5	50
HA-2640/05	±40	5	5	5	1	50
HA-4741	±15	10	2	2	1	50
HA-5101	±15	2	2	2	1	50
HA-5102/04	±15	2	2	2	1	50
HA-5111	±15	2	2	2	10	50
HA-5112/14	±15	2	2	2	10	50
HA-5127	±15	0.6	2	2	1	50
HA-5130/05	±15	0.6	2	2	1	100
HA-5134	±15	2	2	2	1	50
HA-5137	±15	0.6	2	2	5	50
HA-5141/12/14	+5/0	50	50	50	1	50
HA-5147	±15	0.6	2	2	10	50
HA-5151/12/14	±15	10	10	10	1	50
HA-5160/62	±15	2	2	2	10	50
HA-5170	±15	2	2	2	1	50
HA-5180	±15	2	2	2	1	50
HA-5190/95	±15	0.2	0.2	2	5	10

Test Circuits
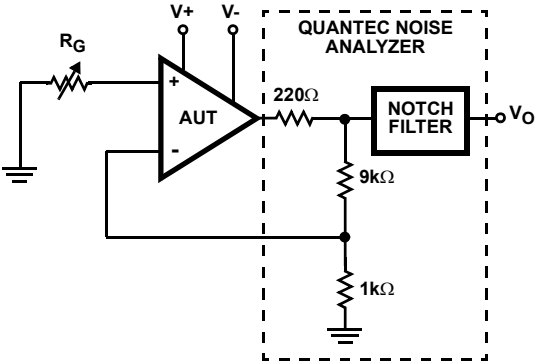

TEST CIRCUIT 1
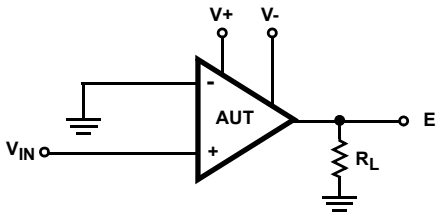
TEST CIRCUIT 2
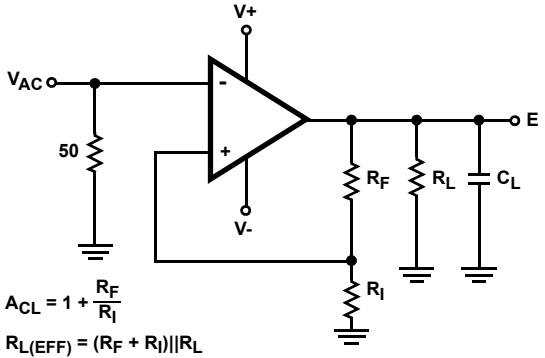
$$A_{CL} = 1 + \frac{R_F}{R_I}$$

$$R_{L(EFF)} = (R_F + R_I)||R_L$$

TEST CIRCUIT 3

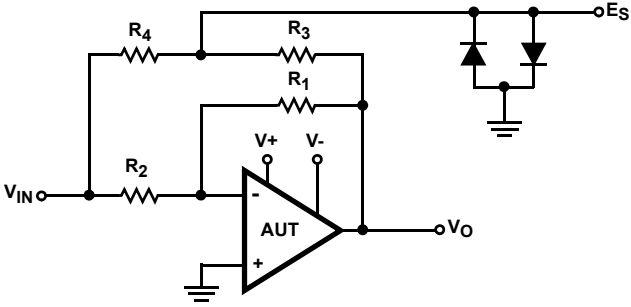**TEST CIRCUIT 4**

TEST CIRCUIT 5

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Test Circuits (Continued)

TEST CIRCUIT 6

CHANNEL 1
(INPUT CHANNEL)

CHANNEL 2
(LEAKAGE CHANNEL)

TEST CIRCUIT 7

RENESAS
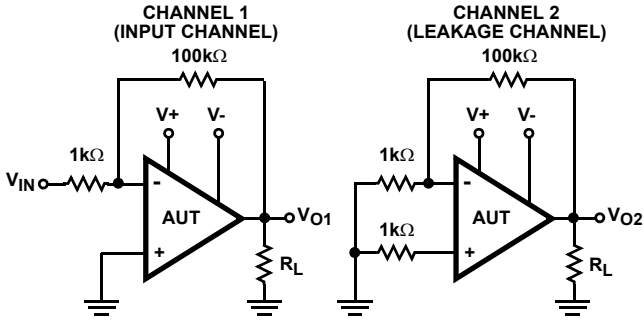
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